

Description

The MOSFET provide the best combination of fast switching , low on-resistance and cost-effectiveness.

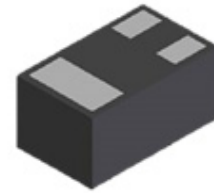
MOSFET Product Summary		
$V_{DS}(V)$	$R_{DS(on)}(m\Omega)$	$I_D(A)$
-20	335 @ $V_{GS} = -4.5V$	-0.8
	405 @ $V_{GS} = -2.5V$	

Feature

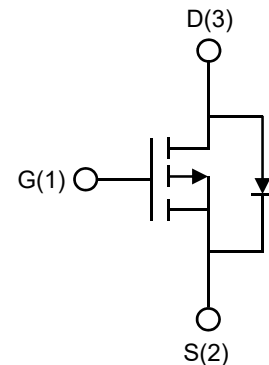
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Applications

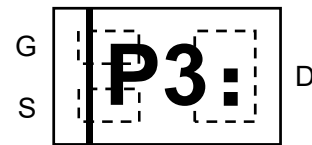
- PWM applications
- Load switch
- Power management
- DC-DC Converters
- Wireless Chargers



**DFN1006-3L
(Bottom View)**



Circuit Diagram



Marking (Top View)

Absolute maximum rating@25°C

Rating		Symbol	Value	Units
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	± 8	V
Drain Current-Continuous ¹⁾	$T_C=25^\circ C$	I_D	-0.8	A
	$T_C=100^\circ C$		-0.5	
Pulsed Drain Current ²⁾		I_{DM}	-3.5	A
Total Power Dissipation ³⁾		P_D	0.5	W
Thermal Resistance , Junction-to-Case ⁴⁾		$R_{\theta JC}$	53.6	$^\circ C/W$
Thermal Resistance , Junction-to-Ambient ⁴⁾		$R_{\theta JA}$	249.8	$^\circ C/W$
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	$^\circ C$

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-20	-23.7	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -20V, V_{GS} = 0V$	-	-	-1.0	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 8V, V_{DS} = 0V$	-	-	± 10	μA
On Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.45	-0.59	-0.9	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS} = -4.5V, I_D = -0.7A$	-	335	700	m Ω
		$V_{GS} = -2.5V, I_D = -0.3A$	-	405	850	
		$V_{GS} = -1.8V, I_D = -0.1A$	-	497	1500	
Dynamic Characteristics⁵⁾						
Input Capacitance	C_{ISS}	$V_{DS} = -10V, V_{GS} = 0V,$ $f = 1.0MHz$	-	12.6	-	pF
Output Capacitance	C_{OSS}		-	15.7	-	
Reverse Transfer Capacitance	C_{RSS}		-	3.8	-	
Switching Characteristics⁵⁾						
Turn-on Delay Time	$t_{d(on)}$	$V_{DS} = -6V, V_{GS} = -4.5V,$ $R_G = 50\Omega, R_L = 12\Omega,$ $I_D = -0.45A$	-	885	-	ns
Turn-on Rise Time	t_r		-	2313	-	
Turn-Off Delay Time	$t_{d(off)}$		-	9463	-	
Turn-Off Fall Time	t_f		-	6613	-	
Total Gate Charge	Q_g	$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_D = -0.45A$	-	0.86	-	nC
Gate-Source Charge	Q_{gs}		-	0.21	-	
Gate-Drain Charge	Q_{gd}		-	0.14	-	
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = -0.15A$	-	-0.76	-1.0	V

Notes:

1. Computed continuous current assumes the condition of T_{J_Max} while the actual continuous current depends on the thermal & electro-mechanical application board design.
2. Repetitive Rating: Pulse width limited by maximum junction temperature($T_{J_Max}=150^\circ C$).
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout
5. Guaranteed by design, not subject to production.

Typical Characteristics

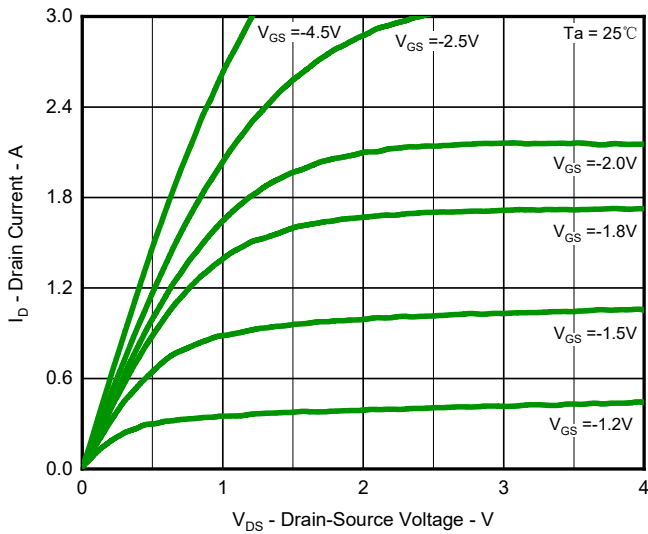


Fig.1 Output Characteristics

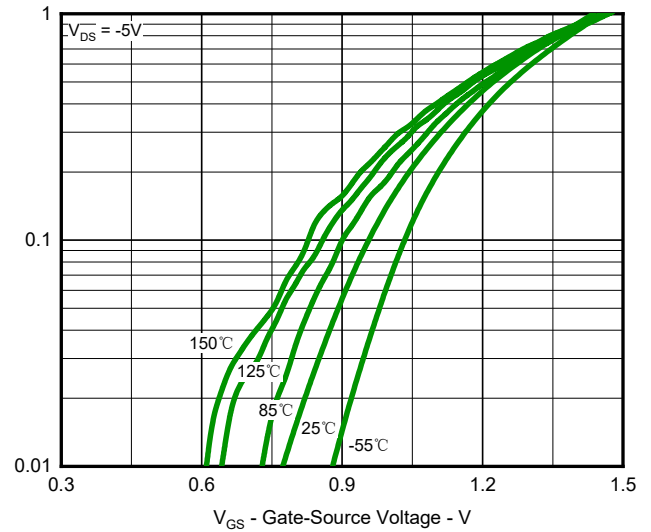


Fig.2 Typical Transfer Characteristic

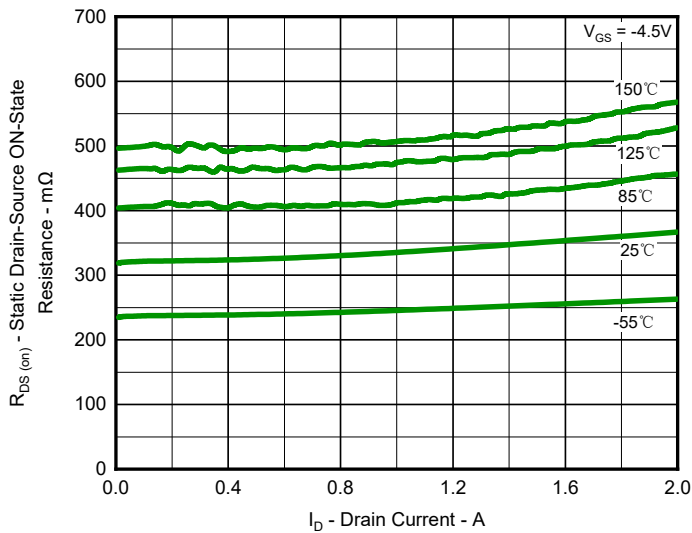


Fig.3 Typical On-Resistance vs Drain Current and Temperature

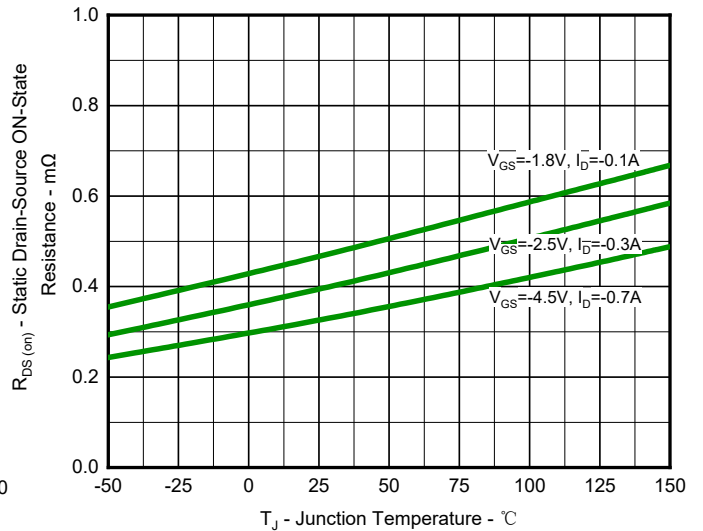


Fig.4 On-Resistance Variation with Temperature

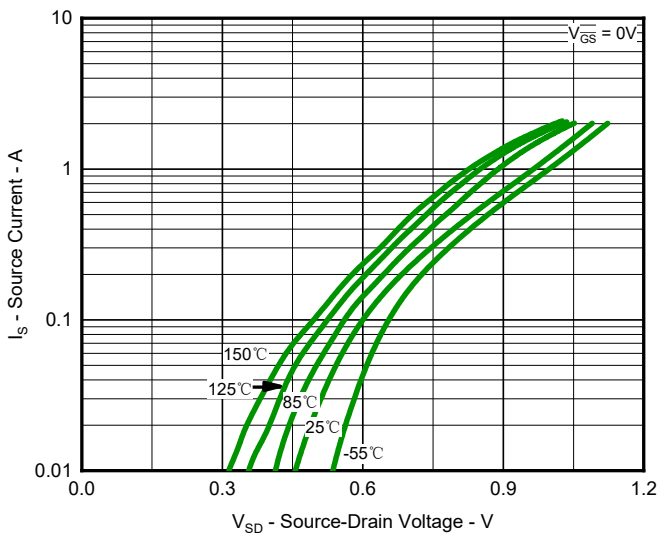


Fig.5 Diode Forward Voltage vs. Current

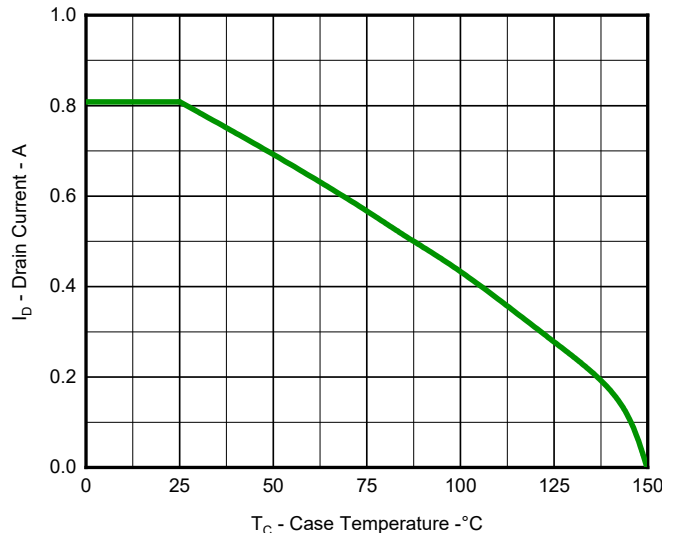


Fig.6 Maximum Drain Current vs. Case Temperature

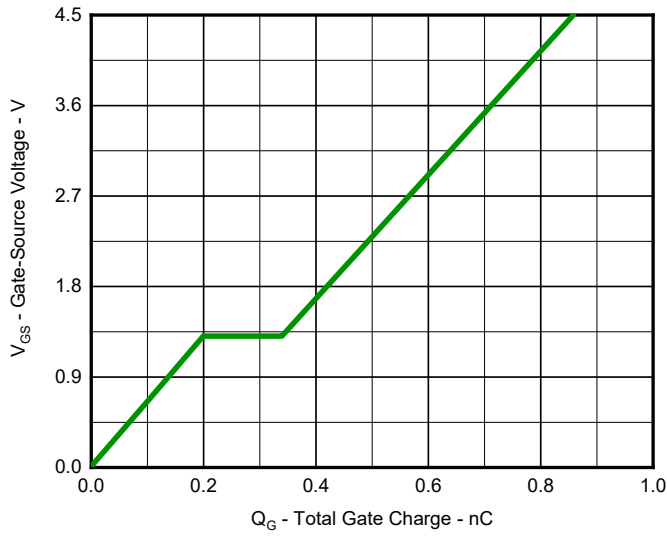


Fig.7 Gate Charge Characteristics

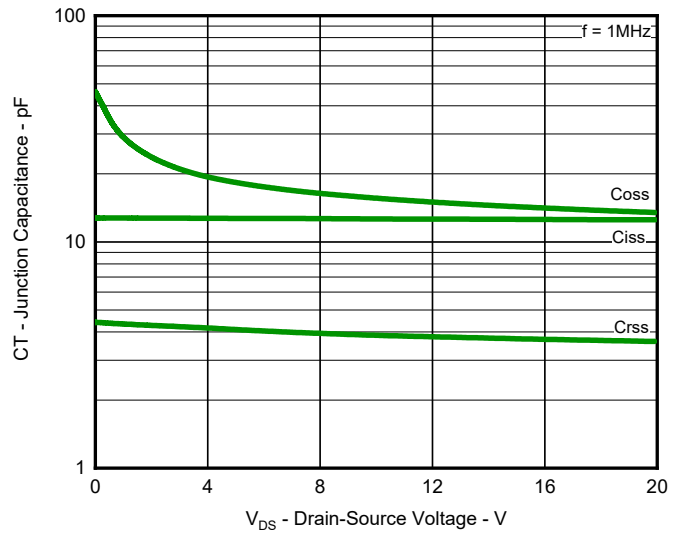


Fig.8 Typical Junction Capacitance

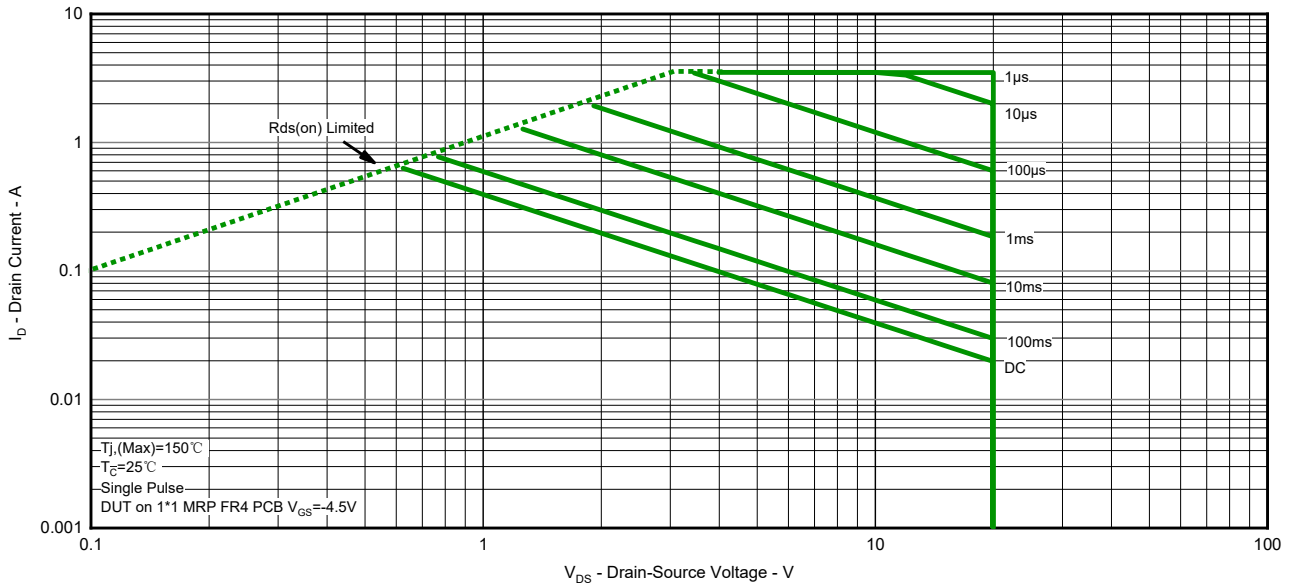


Fig.9 Safe Operation Area

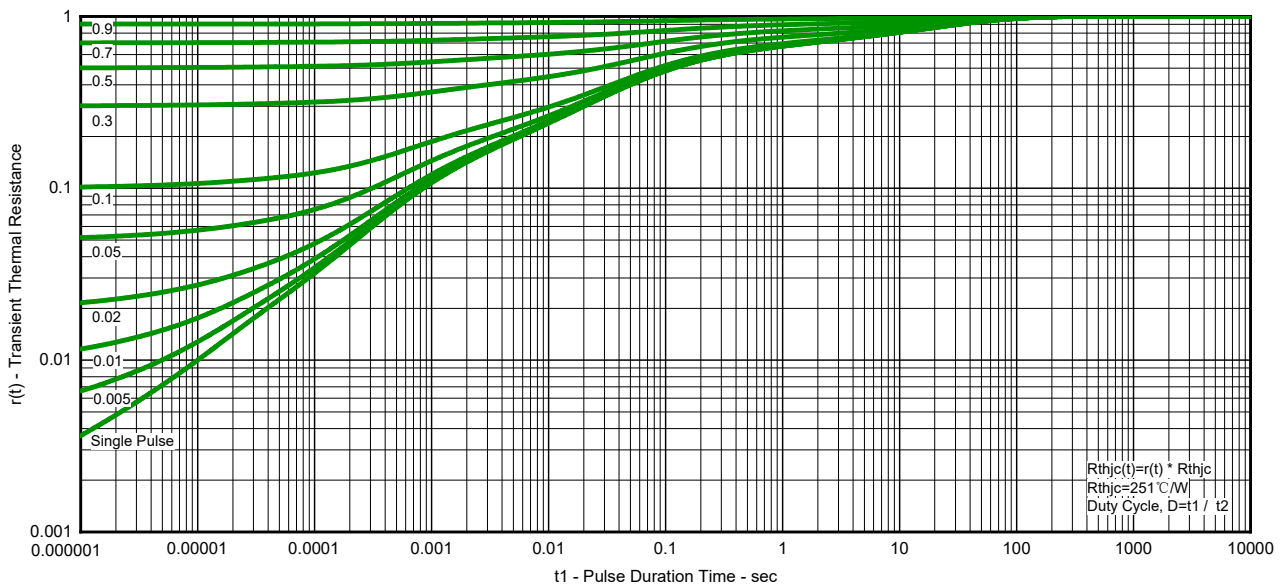
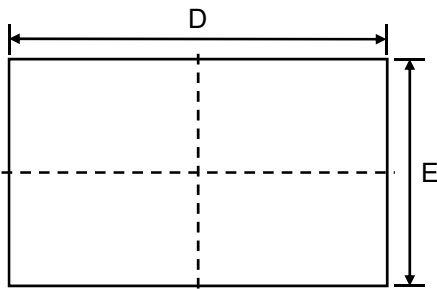
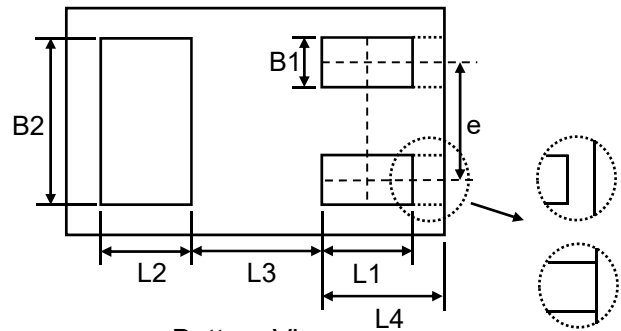


Fig.10 Transient Thermal Resistance

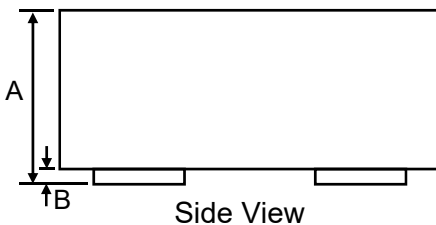
Product Dimension (DFN1006-3L)



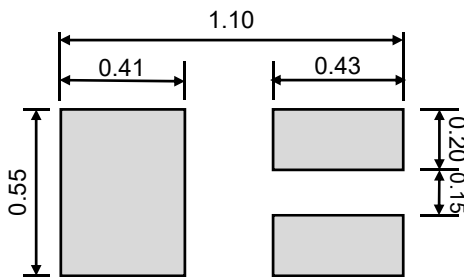
Top View



Bottom View



Side View



Suggested PCB Layout

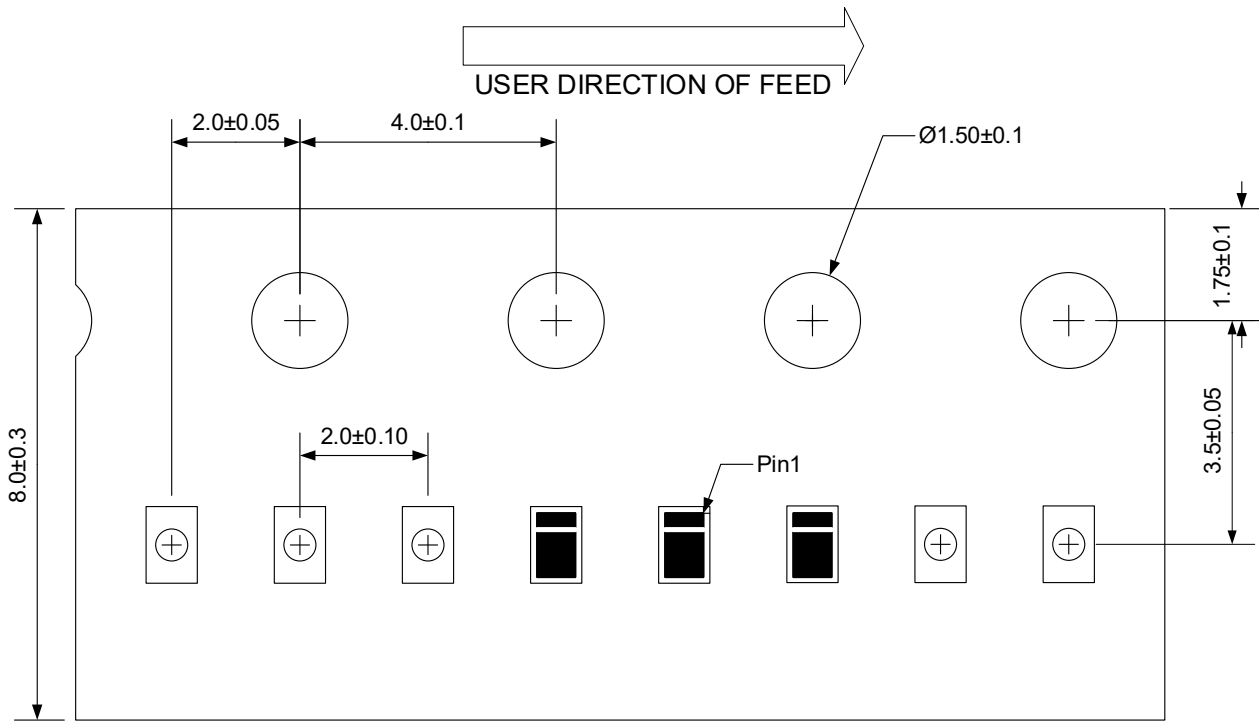
Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	0.33	0.498	0.013	0.020
B	0.00	0.05	0.000	0.002
B1	0.10	0.20	0.004	0.008
B2	0.45	0.55	0.018	0.022
D	0.90	1.05	0.035	0.041
E	0.50	0.65	0.020	0.026
e	0.35		0.014	
L1	0.20	0.30	0.008	0.012
L2	0.20	0.30	0.008	0.012
L3	0.39		0.015	
L4	0.25	0.35	0.010	0.014

Unit: mm

Ordering information


Device	Package	Reel	Shipping
PPM3FD20V1EL	DFN1006-3L(Pb-Free)	7"	10000 / Tape & Reel

Load with information



Unit:mm


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